Preferred Device

Axial Lead Rectifier

...employing the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlap contact. Ideally suited for use as rectifiers in low-voltage, high-frequency inverters, free wheeling diodes, and polarity protection diodes.

- Extremely Low V_F
- Low Power Loss/High Efficiency
- Highly Stable Oxide Passivated Junction
- Low Stored Charge, Majority Carrier Conduction

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.1 gram (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 220°C Max. for 10 Seconds, 1/16" from case
- Shipped in plastic bags, 500 per bag
- Available Tape and Reeled, 1500 per reel, by adding an "RL" suffix to the part number
- Polarity: Cathode indicated by Polarity Band
- Marking: B340

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	V
Average Rectified Forward Current $T_A = 65$ °C ($R_{\theta JA} = 28$ °C/W, P.C. Board Mounting)	lo	3.0	A
Non-Repetitive Peak Surge Current (Note 1) (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz, T _L = 75°C)	I _{FSM}	80	A
Operating and Storage Junction Temperature Range (Reverse Voltage Applied)	T _J , T _{stg}	-65 to +150	°C
Peak Operating Junction Temperature (Forward Current Applied)	$T_{J(pk)}$	150	°C

^{1.} Lead Temperature reference is cathode lead 1/32" from case.



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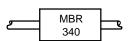
http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 3.0 AMPERES 40 VOLTS



CASE 267-05 (DO-201AD) STYLE 1

MARKING DIAGRAM



MBR340 = Device Code

ORDERING INFORMATION

Device	Package	Shipping		
MBR340	Axial Lead	500 Units/Bag		
MBR340RL	Axial Lead	1500/Tape & Reel		

Preferred devices are recommended choices for future use and best overall value

THERMAL CHARACTERISTICS

Characteristic		Max	Unit
Thermal Resistance, Junction to Ambient (see Note 4, Mounting Method 3)	$R_{\theta JA}$	28	°C/W

ELECTRICAL CHARACTERISTICS (T_L = 25°C unless otherwise noted) (Note 2)

Characteristic	Symbol	Max	Unit
Maximum Instantaneous Forward Voltage (Note 3) $ \begin{aligned} &(i_F = 1.0 \text{ Amp}) \\ &(i_F = 3.0 \text{ Amp}) \\ &(i_F = 9.4 \text{ Amp}) \end{aligned} $	VF	0.500 0.600 0.850	V
Maximum Instantaneous Reverse Current @ Rated dc Voltage (Note 3) $T_L = 25^{\circ}C$ $T_L = 100^{\circ}C$	i _R	0.60 20	mA

- 2. Lead Temperature reference is cathode lead 1/32" from case.
- 3. Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2.0%.

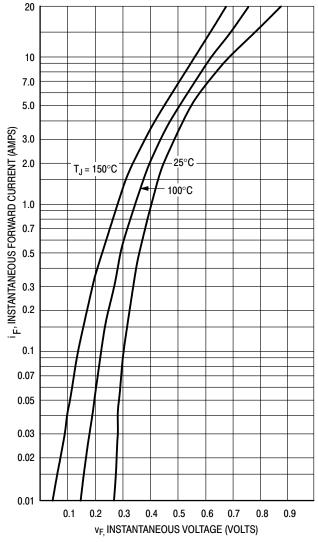


Figure 1. Typical Forward Voltage

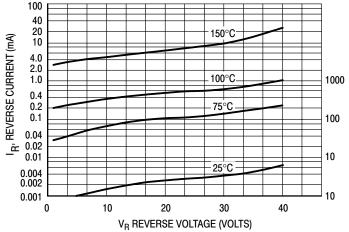


Figure 2. Typical Reverse Current*

*The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

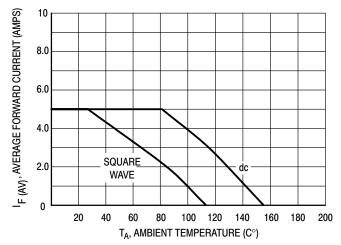
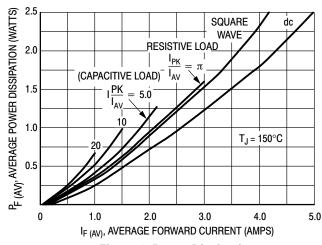


Figure 3. Current Derating (Mounting Method #3 per Note 4)

MBR340



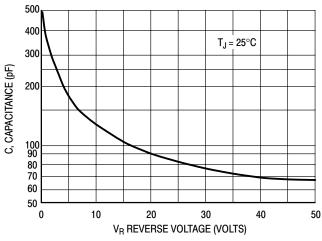


Figure 4. Power Dissipation

Figure 5. Typical Capacitance

NOTE 4 — MOUNTING DATA

Data shown for thermal resistance junction-to-ambient $(R_{\theta JA})$ for the mountings shown is to be used as typical guideline values for preliminary engineering, or in case the tie point temperature cannot be measured.

TYPICAL VALUES FOR $R_{\theta \text{JA}}$ IN STILL AIR

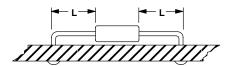
Mounting	Lead Length, L (in)				
Method	1/8	1/4	1/2	3/4	$R_{\theta JA}$
1	50	51	53	55	°C/W
2	58	59	61	63	°C/W
3	28				°C/W

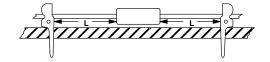
Mounting Method 1

P.C. Board where available copper surface is small.

Mounting Method 2

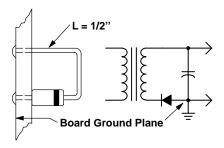
Vector Push-In Terminals T-28





Mounting Method 3

P.C. Board with 2-1/2" X 2-1/2" copper surface.

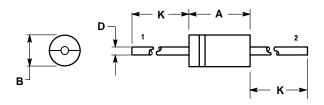


MBR340

PACKAGE DIMENSIONS

AXIAL LEAD

CASE 267-05 (DO-201AD) **ISSUE G**



- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN MAX	
Α	0.287	0.374	7.30	9.50
В	0.189	0.209	4.80	5.30
D	0.047	0.051	1.20	1.30
K	1.000		25.40	

PIN 1. CATHODE (POLARITY BAND) 2. ANODE

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